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**AMENDMENTS TO THE CLAIMS:** 

This listing of claims will replace all prior versions, and listings, of claims in the

application:

**LISTING OF CLAIMS:** 

Claims 1-10 (canceled).

Claim 11 (new): A surface acoustic wave branching filter comprising:

a first surface acoustic wave filter having a ladder-type circuit structure including

a plurality of parallel-arm resonators and a plurality of series-arm resonators, the first

surface acoustic wave filter having a relatively low passband;

a second surface acoustic wave filter having a relatively high passband that is

higher than said relatively low passband; and

a first common terminal to which one end of each of the first and second surface

acoustic wave filters is connected, the first common terminal being connected to an

antenna; wherein

one of the plurality of series-arm resonators and parallel-arm resonators that is

closest to the first common terminal is a parallel-arm resonator and the capacitance of

the parallel-arm resonator that is closest to the first common terminal is less than about

1/2 of the capacitance of another one of the plurality of parallel-arm resonators.

Claim 12 (new): The surface acoustic wave branching filter as claimed in claim

11, wherein the capacitance of the parallel-arm resonator that is closest to the first

common terminal is in the range of about 1/40 to about 1/5 of the capacitance of said

another one of the plurality of parallel-arm resonators.

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Claim 13 (new): The surface acoustic wave branching filter as claimed in claim

11, further comprising a second common terminal to which one end of the parallel-arm

resonator that is closest to the first common terminal and one end of the another one of

the plurality of parallel-arm resonators are connected, and an inductance element is

arranged between the second common terminal and ground potential.

Claim 14 (new): The surface acoustic wave branching filter as claimed in claim

13, further comprising a package material housing the first and second surface acoustic

wave filters, wherein the second common terminal is included in the package material.

Claim 15 (new): The surface acoustic wave branching filter as claimed in claim

11, wherein a resonance frequency of the parallel-arm resonator that is closest to the

first common terminal is substantially the same as the resonance frequency of said

another one of the plurality of parallel-arm resonators.

Claim 16 (new): The surface acoustic wave branching filter as claimed in claim

11, further comprising a phase adjustment element located between the second surface

acoustic wave filter and the first common terminal.

Claim 17 (new): The surface acoustic wave branching filter as claimed in claim

16, wherein the amount of phase delay of the phase adjustment element is less than

about 90 degrees from a central frequency of the first surface acoustic wave filter and,

when seen from the side of the first common terminal, at least about 50% of the

passband of the second surface acoustic wave filter is inductive.

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Claim 18 (new): The surface acoustic wave branching filter as claimed in claim

16, wherein the phase adjustment element includes a stripline.

Claim 19 (new): The surface acoustic wave branching filter as claimed in claim

16, wherein the phase adjustment element includes a capacitance element and an

inductance element.

Claim 20 (new): The surface acoustic wave branching filter as claimed in claim

11, wherein, when seen from the side of the first common terminal, at least about 50%

of the passband of the second surface acoustic wave filter is inductive.

Claim 21 (new): The surface acoustic wave branching filter as claimed in claim

11, wherein said one of the plurality of parallel-arm resonators is located between the

series-arm resonators.